Anomalous Josephson Effect in Andreev Interferometers

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The first evidence of anomalous Josephson effect is reported in mesoscopic superconductor-normal metal-superconductor (SNS) junctions forming a crosslike Andreev Interferometer in the absence of magnetic and spin-orbit interactions normally required to break time-reversal and inversion symmetries. From conductance measurements of the the out-of-equilibrium weak link we determine a voltage-controlled spontaneous phase that resembles a φ_0 -junction. The temperature and voltage dependences together with a dissipative term in the current-phase relation strongly suggest that the mechanism underlying the observed phenomenon relies on electron-hole asymmetries.

The dc Josephson effect establishes that current flows without dissipation across two superconductors interrupted by a weak link in a so-called Josephson junction (JJ) [1]. The supercurrent I_s and the macroscopic phase difference of the superconductors δ are correlated by the current-phase relation (CPR) which hosts some general properties [2, 3] like 2π periodicity and time-reversal symmetry $I_s(-\delta) = -I_s(\delta)$. The latter determines the $I_s(\delta = 0) = 0$ condition and a CPR given by a series of sinusoidal functions. However, most of these junctions are well described by the first harmonic $I_s(\delta) = I_c \sin \delta$ with minimum energy at $\delta = 0$ and therefore called 0-JJs. Under certain conditions, the supercurrent can change its polarity leading to a π ground state. Discovered in nonequilibrium-controlled metallic JJs [4, 5], π -JJs were intensely investigated thereafter in ferromagnetic [6, 7], semiconductor-based JJs [8, 9] or using superconductors with unconventional paring symmetry [10, 11]. However, these JJs still present a rigid ground state given by the supercurrent direction which constrains the flowing Josephson current to $\delta \neq n\pi$ states with n any integer. To date, two mechanisms have been explored to achieve JJs with variable ground states. Those with a large and negative second harmonic that gives rise to a degenerate and arbitrary design-determined $\pm \varphi$ phase [12–14]; and junctions with broken inversion symmetry and a nondegenerate and controllable φ_0 phase bias acting as a Josephson phase battery [15–18]. The former is possible in a combination of $0-\pi$ -JJs owing to spatial oscillations of the Cooper pair wave function [19, 20], ferromagnetic weak links are the most suitable candidates thanks to the ground state dependence on the magnetic layer thickness [21, 22]. In φ_0 -JJs, the interplay of an exchange splitting field and strong spin-orbit coupling (SOC) [23– 25] or noncoplanar magnetic texture [26] induces a finite phase shift

$$I_s = I_c \sin(\delta - \varphi_0) = I_J \sin\delta + I_{an} \cos\delta \qquad (1)$$

with $I_J = I_c \cos \varphi_0$ and $I_{an} = -I_c \sin \varphi_0$ the usual

and anomalous Josephson current. Unlike previous systems, $0-\pi$ transition in metallic junctions is achieved by driving the electrons out-of-equilibrium but φ_0 -states have not been reported so far. However, a recent revision of the quasiclassical Green's function formalism suggested that electron-hole asymmetries may induce nonvanishing Aharonov-Bohm-like currents in multiterminal normal-superconducting heterostructures, frequently called Andreev interferometers [27–29]. The interplay of even-in- δ Aharonov-Bohm oscillations and the normal Josephson currents could be responsible for φ_0 -states in geometrically asymmetric interferometers.

In this letter, we report on the demonstration of metallic and non-magnetic φ_0 -junctions forming mesoscopic crosslike Andreev interferometers known as Hybrid Quantum Interference Device (HyQUID) [30]. The supercurrent of lateral hybrid junctions can be suppressed by modifying the electrostatic potential of the weak link V_N and voltage-controlled φ_0 -states emerge beyond a critical value. First, we discussed the effects of embedding the anomalous junction in a superconducting ring with non-negligible screening currents and the model to determine the phase shift. Later, we present conductance measurements of the proximitized normal wire coupled to the JJs in flux-biased HyQUIDs. Subsequently, the I-V characteristics of the anomalous junctions and the temperature dependence of the interferometers are presented. Finally, we discuss the experimental findings under the hypothesis of voltage-dependent even-in- δ currents competing with odd-in- δ Josephson currents.

We fabricated Nb/Ag/Nb HyQUIDs schematically depicted in Figure 1a which consist of two 300 nmthick superconducting electrodes interrupted by the nonmagnetic 50 nm-thick metal connected to reservoirs in a crosslike geometry (dark yellow). Our junctions exhibit highly transparent S/N interfaces with S-electrodes spaced $L_x = 500$ nm larger than the superconducting ξ_0 and the normal ξ_N coherence length which places our devices in the diffusive and long junction regime. In this limit, the superconducting Josephson correlations are described by a continuous spectrum of supercurrentcarrying density of states (SCS) [31, 32] with a Thouless

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FIG. 1. Positive φ_0 -states in flux-biased HyQUID. (a) Schematic of a HyQUID with the 4-wire electrical configuration for measuring the interferometer (dark yellow) differential resistance R_N as a function of the potencial at the center of the junction V_N and the external flux Φ_e . (b) Motion of a point particle in the flux-tilted washboard potential of the system for $\varphi_0 = -\pi/4$ and $\beta = 10$. At $\Phi_e = 0$, the particle is trapped in a $\delta = \varphi_0$ minimum (black ball). Positive (negative) external flux shifts to the left (right) the Φ_0 -periodic potential and the particle escapes to a lower energy state at $\Phi_n^+(\Phi_n^-)$, red (green) balls. (c) $\delta(\Phi_e)$ for $\varphi_0 = 0$, $-\pi/4$, $\pi/4$. Phase jumps occur at $d\Phi_e/d\delta = 0$ regardless of the ground state. The relation loses its symmetry for $\varphi_0 \neq 0$. (d) Colormap plot of a HyQUID differential resistance as a function of flux with positive sweeping polarity and bias voltages $V < V_N^{c1}$. (e) $R_N(\Phi_e)$ traces for selected voltages with positive (red) and negative (green) flux polarity. $R_N^+(\Phi_n^+) > R_N^-(\Phi_n^-)$ for all the bias voltages. The gray curves are the best fit to the model. A quasi-constant and positive $\varphi_0 = \pi/20$ is obtained. Phase jump transitions are included in the dashed lines.

energy, the characteristic energy scale, $E_{th} = \hbar D/L_x^2 =$ 0.04 meV for a diffusion coefficient $D = 150 \ cm^2/s$. By applying a voltage V_N across the connecting normal wires with a total length $L_N \simeq 4 \ \mu m$, we create a nonthermal quasiparticle energy distribution function. Large reservoirs and a diffusion time $\tau_D = L_N^2/D$ shorter than the characteristic interaction time ensure out-of-equilibrium conditions (see details in Ref. [33]). We conduct measurements on two different configurations of HyQUID, one in which the superconducting electrodes are connected to a four-wire electrical setup in a similar fashion than in Ref. [4, 5], allowing the direct probing of critical current of the junction, and one in which the electrodes are joined to form a loop. The latter allows to control the phase across the junction by the application of a magnetic flux. The junction is embedded in a superconducting loop with an inductance L = 290 pH. As a result, the phase-sensitive metal resistance enters a nonlinear regime with bistable states and a highly φ_0 -dependent

hysteretic behavior [34]. This method allows the anomalous phase to be determined independently of any spurious flux trapped in the system. If the screening parameter $\beta = 2\pi L I_c/\Phi_0 > 1$, the contribution to the net flux due to the supercurrent-induced flux results in a phase difference that is a non-linear function of the external flux Φ_e :

$$\delta = 2\pi \frac{\Phi_e}{\Phi_0} - \beta i = \phi_e - \beta i \tag{2}$$

with $i = I_s/I_c$ the normalized supercurrent and $\phi_e \equiv 2\pi\Phi_e/\Phi_0$ the "external phase". The potential energy for such junctions is given by the Josephson energy and the magnetic energy stored in the loop inductance [35]

$$U = E_J \left[1 - \cos\left(\delta - \varphi_0\right) + \frac{\left(\delta - \phi_e\right)^2}{2\beta} \right]$$
(3)

with $E_J = \Phi_0 I_c/2\pi$. If $\beta < 1$, $\delta \simeq \phi_e$ and the potential energy has a parabolic shape with a single minimum.

For $\beta > 1$, the oscillating component gives rise to several minima and maxima according to the positive and negative slopes of the multi-valued function $\delta(\phi_e)$. $U(\delta)$ presents inflection points at

$$\phi_n^{\pm} = \varphi_0 \pm [\phi_t(\beta) + 2\pi n] \tag{4}$$

at which $\delta(\phi_e)$ slopes change sign. $\phi_t = \sin^{-1}[1/\beta] +$ $\sqrt{\beta^2 - 1} + \pi/2$, see calculations in Ref. [33], varies linearly for large β . For convenience, we use $\Phi \equiv \phi/2\pi$ notation. Under the classical analogy of a particle moving in a "washboard potential", the particle is trapped in a potential minimum U=0 or ground state at zero applied flux. When an external flux is applied, the parabolic part is shifted along the oscillating component and the particle energy increases captured in the potential well. The well barriers decrease with the flux until vanishing at $\Phi_e = \Phi_{n=0}^{\pm}$, the induced supercurrent $I_s = \Phi_n/L$ matches the critical current, a flux quantum enters the loop reducing $|\phi_e - \delta|$, and the particle escapes to a lower energy state in a "phase jump". In φ_0 -JJs, the zero-flux minimum shifts to $\delta = \varphi_0$. The potential remains invariant with respect to the simultaneous change of ϕ_e and δ by $2\pi n$, but the anomalous CPR breaks the phase difference symmetry $\delta(\Phi_e) \neq -\delta(-\Phi_e)$ and the system becomes direction-dependent $\phi_n^+ = -\phi_n^- + 2\varphi_0$ (see Figure 1b,c).

The differential resistance R_N of Andreev interferometers is measured at T = 2.7 K as a function of the external flux and the voltage at the center of the wire given by $V_N = I_N R_N(0)/2$. I_N is the bias current applied to the connecting wire and $R_N(0)$ the differential resistance at zero bias current. At this temperature, $\xi_N = \sqrt{\hbar D/2\pi k_B T} \simeq 83$ nm. All devices exhibit similar resistance $R_N(0) = 1.8(2)\Omega$. The conductance of the connecting wires oscillates as a function of the phase difference δ due to phase transfer from the superconducting condensate to normal electrons via Andreev reflections at the S/N interfaces [36] with a minimum resistance R_N^0 at $\delta = (2n+1)\pi$ [37], thereby it can be approximated by

$$R_N = R_N^0 - \frac{\Delta R}{2} [1 + \cos \delta] \tag{5}$$

where ΔR depends on the properties of the system (see Ref. [33] for a quantitative study of $\Delta R(V_N)$). We varied the inductively applied flux back and forth starting from a negative initial flux. A sign convention is chosen for positive (+) and negative (-) polarity of the flux sweep. $\delta(\Phi_e)$ becomes multi-valued for $I_c > 0.9 \ \mu A. \ R_N(\Phi_e, V_N)$ colormap is shown in Figure 1d for $V_N < V_N^{c1} = 0.26 \text{ mV}.$ Gray curves are the best fit to the model given by Equations 1, 2 and 5 with the phase jumps (dashed trajectories) obtained from Φ_n^{\pm} and $\Delta R, \beta, \varphi_0$ the fitting parameters. By referencing the initial phase jump to the first resistance minimum, $\Phi_{n=0} \equiv \Phi_{n=0} - \Phi(\delta = 2n\pi)$, the model becomes insensitive to any horizontal displacement, e.g., by trapped flux. $\Phi_{n=0}$, which is followed by Φ_0 -periodic jumps (bright areas), decreases monotonically until the critical current is suppressed at $eV_N^{c1} \simeq 7E_{th}$ where the system becomes fully periodic. Resistance at phase jumps is slightly lower when the flux is negatively swept $R_N^+(\Phi_n^+) > R_N^-(\Phi_n^-)$, (see Figure 1e) explained by a small and quasi-constant anomalous current $I_{an} < 0$ corresponding to $\varphi_0 = +\frac{\pi}{40}(2\pm 1)$. For large β , the resulting state of the phase jumps are not the one with the lowest energy. If barriers are overcome, e.g., by thermal fluctuations, several flux quanta may enter the loop and the system falls to a much lower energy or materialize at $\Phi^* < \Phi_n$. These phenomena are observed for almost any voltage (blue areas in the periodic jumps region) regardless of the flux polarity. Notwithstanding the above, the model adequately tracks these anomalies as the system remains trapped in the next available potential well as the gray lines shown.

The reflection symmetry is fully broken above V_N^{c1} , clear signature of the anomalous behavior (Figure 2a,b). $R_N^{\pm}(\Phi_e)$ become non-periodic owing to screening currents $\beta > 1$, but supercurrent is not reversed as expected in symmetric interferometers. R_N^+ shows rounded minima and a sawtooth pattern with jumps from high to low values for both flux polarities. As the bias voltage increases, the resistance jumps in R_N^- do not drop to the lowest resistance state and the curves become hysteretic. The height of the resistance jumps progressively decreases in R_N^+ and the gap between the curves increases. This behavior is well described by a monotonic increase of both the screening currents and a negative phase shift $0 < |\varphi_0| < \pi/2$. The sign change in φ_0 means that only I_{an} is reversed. At $V_N = 0.38 \text{ mV}, R_N^+$ jumps disappear at $\varphi_0 = -\pi/4$ and $\beta \simeq 11$ meaning that $|I_{an}| = |I_J|$. Beyond this point (purple zone), R_N^+ reaches the minimum value and remains constant with some traces of small jumps from low to high resistance states, meanwhile R_N^- jumps are progressively rounded and the maximum resistance R_N^0 is reached. The model predicts small phase jumps in R_N^+ for larger $|\varphi_0|$ with a flip in the direction of the resistance jumps at $\varphi_0 \simeq -\pi/3$ and maximum screening currents. Above $V_N^* \simeq 0.44$ mV, R_N^- peaks disappear, the resistance smoothly reaches the maximum allowed values and remains constant, consistent with the inversion of I_J , $\pi > |\varphi_0| > \pi/2$. Phase jumps in R_N^- are expected to disappear for $\varphi_0 = -l \pi/6$ and $\beta > 5$ with $l \in 4-5$ as it is shown for $V_N = 0.56$ mV. The onset of R_N^- resistance jumps in the green zone with rounded maxima is explained by the decrease of $|\varphi_0|$ and the screening currents that pull the R_N branches apart for $\beta < 5$ and $\varphi_0 \rightarrow -2\pi/3$. R_N^- recovers the sawtooth shape with a similar profile than R_N^+ for $V_N > 0.63$ mV, consistent with a CPR controlled by I_{an} , $\varphi_0 \simeq -\pi/2$. The gap decreases and the system becomes periodic and fully symmetric $R_N^- = R_N^+$ for $V_N > 0.68$ mV. Clear evidence of



FIG. 2. Voltage-controlled φ_0 -states in flux-biased HyQUID. (a) Colormap plot of the HyQUID differential resistance for positive (left) and negative (right) sweeping flux polarity above V_N^{c1} . The evolution is described by zones (dashed squares) in text. (b) Characteristic R_N^+ (red) and R_N^- (green) traces for each zone at $V_N = 0.33$, 0.4, 0.56 and 0.67 mV. The gray line is the best fit to the model. The blue and cyan dashed lines are the energetically stable states considering the phase jumps for each curve. (c) Effective critical current $|I_c|$ and φ_0 -states as a function of the bias voltage. After the supercurrent is suppressed at V_N^{c1} , the system loses mirror symmetry consistent with an increasing and negative φ_0 ($|\varphi_0| \le \pi/3$). The usual Josephson current I_J reverses at $V_N^* \simeq 0.44$ mV with a jump discontinuity according to the model. The system eventually tends to a state dominated by the anomalous Josephson current with $|I_c| \rightarrow 0$ and $\varphi_0 = -\pi/2$.

 π -states was not observed in any measured devices. For $|\varphi_0| = \pi$, R_N is not tilted and the resistance branches cross near their maximum value at a given flux $\Phi^*(\beta)$. For $V_N \in V_N^* - 0.5$ mV, we assumed that the escape rate from the potential well is non-negligible at $\Phi^* < \Phi_n$ and the model can fit the data considering the initial curvature and the R_N^+ jumps. The fitting parameters are plotted in Figure 2c with a jump-like transition to quasi- π states at V_N^* . Thermal activated phase jumps (TAPJ) around V_N^* are discussed in Ref. [33].

We measured the differential resistance of the junction as a function of the bias voltage applied as before in current-biased interferometers sketched in Figure 3a. The I-V characteristics, obtained by integration, for selected V_N values are shown in Figure 3b. I_c decreases monotonically mimicking the results obtained in fluxbiased HyQUIDs with a fully resistive state at a similar critical value V_N^{c1} . The persistent current emerges for higher voltages until it vanishes definitively at $eV_N^{c2} \simeq$ $0.9 \text{ meV} \simeq 22E_{th}$. In addition, a dissipative and voltagedependent current I_0 displaces the superconducting region I_s (gray area). I_0 scales linearly with the applied voltage up to $V_N \simeq 0.7$ mV, beyond which thermal effects undermine phase-coherence correlations as shown in long junctions [33]. Measurements in sample B with reversed polarity $I_0(-V_N) < 0$ rules out any leakage currents from the control wires to the superconducting electrodes [38].

We investigated the temperature dependence of the critical voltage in flux-biased HyQUIDs by measuring the voltage to flux relation as a function of the bias voltage with a standard flux-modulation readout scheme [39]. The magnetic flux is swept with a triangular wave on top of a high-frequency and $\Phi_0/2$ amplitude modulation flux. At the critical voltages, $V(\Phi_e)$ is Φ_0 -periodic and equivalent to the voltage to phase relation with maximum peak-to-peak voltage ΔV . Elsewhere, $\delta < 2\pi \Phi_e/\Phi_0$ and $V(\delta)$ cannot be inferred. $\Delta V(V_N)$ for all measured devices present a characteristic two-peak shape as shown in Figure 4a with little variation in V_N^{c1} . According to the existing theory [31, 32], the amplitude and direction of the supercurrent is given by the occupation of the density of states travelling parallel to the phase gradient and



FIG. 3. Current-biased interferometers. (a) False-colored scanning electron micrograph (SEM) of the junction (superconducting electrodes in blue) with the 4-wire electrical configuration for measuring the junction differential resistance as a function of the bias current I. (b) Current-voltage characteristics for selected voltages at the center of the metal $V_N > 0$ (sample A) and $V_N < 0$ (sample B). The voltage-controllable superconducting region I_s is marked in gray. A voltage-dependent shift I_0 is observed in all the anomalous interferometers. The curves are horizontally offset for clarity. (c) Characteristic parameters of the anomalous junctions. The sample-dependent shift is linear for $V_N < 0.7$ mV.

those carrying the supercurrent in the opposite direction. The electrostatic potential depopulates the states with $\epsilon < eV_N$. A temperature-rounded, staircase-like nonequilibrium distribution [40] allows the selective depopulation of positive states whose effectiveness is undermined by temperature, increasing V_N^{c1} until the supercurrent is no longer reversed. In our HyQUIDs, the critical voltage remains constant with temperature up to $T \ge 6$ K. The expected values are plotted together with the experimental values in Figure 4b. Details of the calculations in Ref. [33]. The fact that the theoretical $V_N^{c1} \simeq V_N^*$ suggests that the anomalous current modifies the SCS and reduces the critical voltage.

The underlying physics behind the AJE is now discussed. Spin-orbit interactions and/or a non-coplanar spin structure can be ruled out as the driving force since we used non-magnetic metals and the characteristic Kondo upturn caused by magnetic impurities in the temperature dependence of the resistance was not observed. Unconventional pairing symmetries are not expected in Nb-based devices and the evolution of the differential resistance cannot be fitted if higher harmonics are considered. We also considered the dimensionality of our systems given by the normal coherence length. The devices presented here are two-dimensional structures since $\xi_N < L_x = L_y$. We e-beam patterned the metal crosses in finer HyQUIDs with similar S/N interfaces and trans-



FIG. 4. Temperature dependence of flux-modulated HyQUID. (a) Characteristic two-peak pattern of the peak-to-peak output voltage $\Delta V(V_N)$ with Φ_0 -periodic $V(\Phi_e)$ at $V_N^{c1,c2}$. (b) Temperature dependence of V_N^{c1} compared to theoretical values. V_N^{c1} remains constant until vanishing at T > 6 K.

parency but narrower weak links and control wires $L_y \simeq 100$ nm. AJE is still noticeable in these devices despite the smaller critical currents (details in Ref. [33]). Nevertheless, the dissipative $I_0(V_N)$ and Aharanov-Bohm-like I_{AB} terms in the CPR were predicted in topologicallymodified interferometers [28, 29] which might stem from irregular interfaces [41]. For $eV_N \gg E_{th}$ and highly transparent interfaces I_{AB} are expected to be comparable with I_J resulting in $\varphi(V_N)$ -junction-states. The exponential decay of the Josephson currents [42] with temperature weaker than the $I_{AB} \propto 1/T$ [43, 44] would explain the anomalous temperature dependence and $\pi/2$ -states at large voltages [27].

In summary, our work reveals the first evidence of a voltage-controlled anomalous Josephson effect in metallic and non-magnetic SNS junctions configured as Andreev interferometers. The φ_0 -states can be tuned by modifying the metal electrostatic potential and probed in flux-biased junctions. Our model provides a route to unambiguously determine the current-phase relation if large screening currents are present. These investigations are aligned with recent efforts to implement quantum elements for superconducting electronics such as Josephson phase batteries [15, 17], SNS-transistors [45, 46], memory devices [47–49] or logic circuits [50, 51]. HyQUIDs do not require side gates to control the electron density in semiconductor-based φ_0 -junctions, complex 2DEG systems or scarce unconventional superconductors. Future works should focus on comprehending the role of irregular interfaces in the anomalous effect and on the implementation of hybrid φ_0 -interferometers whose reentrance phenomena [44, 52] occurs at standard qubit operation temperatures.

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Supplemental Information: Anomalous Josephson Effect in Andreev Interferometers

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I. FABRICATION AND METHODS

Hybrid Quantum Interference devices based on a single metallic Josephson Junction (SNS-JJs) forming an Andreev Interferometer were fabricated combining facilities over three sites: JEOL Nanocentre at York and RISE and Albanova, at KTH in Stockholm. The HyQUIDs were manufactured at wafer scale using a multilayer approach. Patterning performed by optical lithography used an Iline stepper, exposing single or bilayer resists as appropriate. First, a Ti/Au (8/500 nm) bilayer was patterned and thermally evaporated to form the contact pads, tracks and 3 x 3 μm^2 metallic reservoirs with a double-layer photoresist to ensure a smooth interface with the metallic interferometer. A 50 nm Ag layer is then evaporated to shape the metallic part of the HyQUID. Residual impurities are removed by O_2 -plasma dry- and HF wet-etching prior to Ag deposition. The length of the vertical branch of the cross-like metallic layer is fixed to $L_N = 4 \mu m$. Junctions with weak link lengths between 0.5 - 1.0 μm were fabricated to investigate their effect on the critical current and test the existing theory (see Section II). Afterwards, we deposited 500 nm of insulating SiO_2 by plasma-enhanced chemical vapor deposition (PECVD). Window vias were created by $CHF_3 + O_2$ reactive ion etching to pattern the superconducting electrodes and the washer-like loop. To achieve high transparency, the interfaces were Ar-etched in situ before sputtering the superconducting Nb (300 nm). A similar process was followed to pattern subsequent Nb layers to form the input (IC) and modulation (MC) coils for magnetometry and on-chip flux line, respectively; and the superconducting tracks to the chip pads (320/520 nm). A 52-turn spiral IC was designed to maximize the coupling. Self- and mutual- inductances were calculated by Ansys in good agreement with the experimental measurements. $M_{IC} =$ 9 nH, $M_{MC} = 67$ pH. Quasi-one-dimensional HyQUIDs with finer features were independently fabricated using the Raith 50 kV Voyager system at University of York. E-beam patterned HyQUIDs were designed with a large S/N interface area ratio (0.6 x 0.4 μm^2) and narrower weak links and control wires $L_y = 0.1 \ \mu m$ compared with the wire length. Optical and electronic (SEM) images of a HyQUID and the e-beam patterned interferometer prior to sputtering the superconducting electrodes together with a scheme of the lock-in technique used in flux-biased experiments are shown in Figure 1. An ac current of 0.7 μ A well below I_c was used to measure the differential resistance. For the flux-modulation readout, a 100 kHz signal was applied via the flux-line combined with a 10 Hz signal. The frequency difference allows to obtain the voltage to flux response by choosing an appropriate time constant.

II. QUASSICLASSICAL THEORY IN LONG AND SHORT HYQUIDS

We validated the existing theory in our HyQUIDs which provides a valuable tool to customize future designs depending on the required application. The performance of the HyQUIDs was investigated as a function of the weak link length using the flux-modulation scheme and relevant paramaters obtained. All devices with weak link lengths $L_x = 0.5 \ \mu \text{m}$ and 0.6 μm exhibit a Φ_0 -periodic voltage to flux relation only at critical voltages $V_N^{c1,c2}$ due to screening currents as in Figure 4a of the main text. For $L_x = 0.8$ and 1.0 μ m, the voltageto-flux curves are periodic for any bias voltage, which means that the screening currents are negligible, $\beta \leq 1$ consistent with the length dependence of the critical current on the long-junction limit $I_c \propto l_x^3 \exp(-l_x)$. l_x is the length normalized by the normal coherence length ξ_N [1]. Therefore, $V(\Phi_e)$ matches the voltage to flux relation and the amplitude of the oscillations as a function of the electrostatic potential, $\Delta V(V_N) = \frac{V_N}{R_N^0} \Delta R$ can be investigated by the quasiclassical Green's function theory (see Figure 2a). $\Delta V(V_N)$ rapidly increases up to $V_N \simeq$ 0.7 mV and then decreases to zero. This behavior can be quantitatively understood by considering the proximity effect approximation [2–4]

$$\Delta V = \int_{-\infty}^{\infty} f_T(\epsilon, eV_N, T) m(\epsilon) d\epsilon$$
(1)

$$f_{L,T} = \frac{1}{2} \left[\tanh\left(\frac{\epsilon + eV_N}{2k_bT}\right) \pm \tanh\left(\frac{\epsilon - eV_N}{2k_bT}\right) \right] \quad (2)$$

 $f_{L,T}$ are the (anti-) symmetric part of the quasiparticle occupation probability in the time-independent diffusive limit of the Boltzmann equation [5]. These functions only consider dissipative currents but not proximity effects. However, Andreev reflections are included in the boundary conditions with respect to the chemical potential, μ_s at the interfaces. If we assume that μ_s is equal

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FIG. 1. Hybrid Quantum Inteference Device (HyQUID) and experimental setup. (a) Optical micrograph of a HyQUID including the washer-like superconducting loop (W) and the on-chip flux line or modulation coil (MC). (b) Scanning electron micrograph (SEM) of the e-beam patterned Andreev interferometer prior to sputtering of the S-electrodes. (c) Scheme of the lock-in technique used in flux-biased experiments.

to the potential at the center of the cross, $f_{L,T}$ are given by the equilibrium occupation probability of the reservoirs which are Fermi distributions with relative potential $\pm eV_N$. The conductance correction due to the superconducting electrodes $m(\epsilon)$ in the diffusive regime can be calculated using the Usadel equation [6]. In the linear approximation and mirror symmetry (see e.g [7])

$$m(\epsilon) = \frac{r}{16} (1 + \cos \delta) \left(\operatorname{Re} \left[\frac{F_s^2}{(\Theta \cosh \Theta_t)^2} \frac{\sinh 2\Theta - 2\Theta}{\Theta} \right] - \frac{|F_s|^2}{|\Theta \cosh \Theta_t|^2} \left[\frac{\sinh 2\Theta'}{\Theta'} - \frac{\sinh 2\Theta''}{\Theta''} \right] \right)$$
(3)
$$\Theta = L_N k: \quad \Theta_t = (L_N + L_x) k$$
$$F_s^2 = \Delta^2 / [\Delta^2 - (\epsilon + i\Gamma)^2] k^2 = 2i\epsilon / hD + 1/L_{\phi}^2$$

where $r = R_{sns}/2R_{sn}$ is the ratio between the weak link and the S/N interface resistances, k is a parameter that depends on the metal properties, the diffusion coefficient D and the phase-breaking length L_{ϕ} . The contribution of the superconductors to $m(\epsilon)$ is given by the imaginary and real part of the condensate Green's function F_s that depends on the superconducting gap Δ and Γ the depairing rate in the superconductor. For energies $\epsilon < \Delta$, $Im(F_s) \sim 0$ and $Re(F_s) \sim 1$ decaying exponentially beyond the Thouless energy (see e.g. ref 32 of the main text). First, we assumed voltage-independent parameters except for the local electron temperature given by $T_e^2 = T^2 + (aV_N)^2$ with a = $\mathfrak{L}^{-0.5} = 6.4$ K/mV and \mathfrak{L} the Lorentz number. For $V_N < 0.7$ mV, the shape and maximum amplitude depend mainly on the diffusion coefficient and the resistance ratio similar to the experimental values. For $V_N > 0.7$ mV, the model predicts a constant amplitude beyond the maximum, but decays similarly to the dissipative current I_0 of the CPR. We introduce a phenomenological effective superconducting gap Δ_{eff} to deal with the thermal effect on the electrodes as $E_{th}(L_x = 1\mu m) \simeq 0.01$ meV $\ll \Delta_{BCS} = 1.5$ meV for Niobium. Then, we introduced the electronic temperature on the metal properties. The phase breaking length $L_{\phi} = (D\tau_{\phi})^{1/2}$ is given by the characteristic timescale of the quasiparticle interactions. At T > 1 K, the electronphonon scattering τ_{ep} is not negligible compared to the electron-electron interactions τ_{ee} and L_{ϕ} is given by

$$\tau_{\phi}^{-1} = \tau_{ee}^{-1} + \tau_{ep}^{-1} = A_{ee}T^{2/3} + A_{ep}T^3 \tag{4}$$

in the absence of other interactions. A_{ee} was calculated from the control wire features and $A_{ep} = 2.2 \cdot 10^7 K^{-3} s^{-1}$ taken from a previous work with similar Ag wires [8]. The introduction of the electronic temperature in Equation 4 is only necessary for e-beam samples where superconducting correlations survive at higher potentials (not shown). The final decay of the correlations can be explained by $\Delta_{eff} = \beta \Delta(T)$ much smaller than the bulk gap with $\Delta(T) = \Delta(0)[1 + (T_{sc}/T_c)^2]^2$ according to the BCS theory. The characteristic voltage-phase relation and $\Delta_{eff}(T)$ are plotted in Figure 2b,c. The temperature of the electrons T_e and the superconducting electrodes T_{sc} differ from the bath temperature [9]. T_{sc} is given by the same formula as the electronic temperature with a rate parameter b that depends on the thermal link between the control wires and the electrodes. Table I shows the parameters obtained for 1 μ m-long HyQUIDs

The dependence of the supercurrent with the temper-



FIG. 2. HyQUID theory. (a) Amplitude of the voltage oscillation on $L_x = 1 \ \mu m$ flux-modulated HyQUIDs and best fit to the model (red line). (b) Characteristic voltage to flux relation $V(\Phi)$. (c) Normalized effective superconducting gap of the Nb electrode, Δ_{eff} . (d) Calculated critical current of $L_x = 0.5 \ \mu m$ HyQUIDs as a function of temperature. I_c is obtained by integration of the (e) supercurrentcarrying density of states (black) and the antisymmetric part of the occupation probability. The curves correspond to 0.1 K (red) and 2.7 K (green).

TABLE I. HyQUID parameters obtained from the fittings to the quasiclassical model in samples with $L_x=1 \ \mu$ m-long junctions. $\Gamma = 0.1\Delta$, b and β define the effective superconducting gap.

D (cm^2/s)	150
r	2.1
$A_{ee} \; (\mathrm{K}^{-2/3} s^{-1})$	$0.96 \cdot 10^8$
$L_{\phi} \ [2.7 \text{ K}](\mu \text{m})$	4.9
b (K/mV)	2.5
β	0.03

ature and voltage is given by

$$I_{sc}(V_N, T, \delta) = \frac{1}{2eR_{sns}} \int_{-\infty}^{\infty} J(\epsilon, \delta) f_L(\epsilon, V_N, T) d\epsilon \quad (5)$$

where R_{sns} is the normal state resistance of the junction, $J(\epsilon, \delta)$ the imaginary part of the energy spectrum of the supercurrent carrying states (SCS) in the normal region and $f_L(\epsilon, V_N, T)$ the antisymmetric part of the occupation probability. In normal junctions, the supercurrent matches the critical current at $\delta = \pi/2$. We use $J(\epsilon, \pi/2)$ from reference 32 and the temperature-rounded step distribution f_L to calculate the critical current $I_c(V_N)$ for selected temperatures (Figure 2d,e) and the theoretical V_N^{c1} plotted in Figure 4b of the main text.

III. THERMALLY ACTIVATED PHASE JUMPS

In this section, thermally activated phase jumps (TAPJ) in flux-biased HyQUIDs are discussed. At zero

temperature, phase jumps take place at potential energy inflection points. First, we demonstrate its equivalence to sign changes in the slope of $\delta(\phi_e)$, independent of φ_0 . From Equation 2 and 3 of the main text:

$$\frac{1}{E_J}\frac{d^2U}{d\delta^2} = \cos(\delta - \varphi_0) + \frac{1}{\beta} = \frac{1}{\beta} \cdot \frac{d\phi_e}{d\delta} = 0 \qquad (6)$$

Then, ϕ_n^{\pm} can be obtained by introducing the inflection point condition

$$\delta = 2\pi n + \cos^{-1}\left(-\frac{1}{\beta}\right) + \varphi_0 \tag{7}$$

in Equation 2 and using the trigonometric identity $sin(cos^{-1}x) = \sqrt{1-x^2}$. A phase jump at $\Phi_e < \Phi_n$ and/or the entry of more than one flux quanta into the loop at the critical flux require overcoming the potential well barriers that protect the ground state. Unlike a phase-slip event in which there is a $\Delta \delta = 2\pi$ change of the phase difference due to thermal activation or quantum tunneling, $\Delta \delta$ in HyQUIDs will depend on the strength of the screening currents due to the $\delta(\Phi)$ non-linearity. TAPJ are easily distinguishable in our flux-biased experiment below V_N^{c1} (see Figure 1 in the main text). For $V_N > 0.5$ mV, good agreement between the experimental data and the model is achieved with a decreasing $|\varphi_0|$ and β until the system is fully dominated by the anomalous Josephson current. The model accounts for the absence of phase jumps in $R_n^-(\Phi_e)$ with a maximum $|\varphi_0| = 5\pi/6$ and sufficiently large screening parameter, but the evolution of the ground state suggests that the usual Josephson current reverses $\varphi_0 \simeq -\pi$ at $V_N^* = 0.44$ mV. However, the expected phase jumps are not observed near V_N^* . We studied the escape probability of the potential well at a given applied flux $\Phi^* < \Phi_n$ with a phase shift that will



FIG. 3. Thermally activated phase jumps in HyQUID. (a) Potential well barrier height as a function of the flux distance to the critical flux $\Phi_n - \Phi^*$ and the screening parameter β . (b) Escape probability of the potential well by thermal activation at T = 2.7 K for $\beta = 4$ and 12. (c) Flux-tilted washboard potential expected at V_N^* ($\varphi_0 = -\pi$ and $\beta = 12$) for zero flux (dashed line), the critical flux (cyan line) and $\Delta \Phi^* = \Phi_n - \Phi^*$ with $P_e(\Phi^*) = 0.5$. Arrows depict the zero and the thermally activated phase jumps. (d) $\delta(\Phi)$ and phase jumps (dashed lines) with the same color scheme. (e) Experimental differential resistance at $V_N^* = 0.44$ mV. The gray line represents the best fit considering the initial curvature and the spontaneous phase jumps. Detailed discussion in text.

not generate any resistance jump (due to the even parity of the cosine function). The thermally activated escape rate from the potential well is given by

$$\Gamma_0 = \omega_A / 2\pi \exp[-U_0 / (k_B T)] \tag{8}$$

where ω_A is the frequency of the escape attempt and U_0 is the β -dependent barrier height of the well. For a flux difference, $\Phi_n - \Phi^* \ll 1/2\pi\beta^3$, U_0 can be approximated by a cubic potential [10]

$$U_0 = 2/3 \sqrt{(1 - \beta^{-2})} E_j \epsilon^3 \tag{9}$$

where

$$\epsilon = \sqrt{\frac{2\pi(\Phi_n - \Phi)}{\sqrt{\beta^2 - 1}}} \tag{10}$$

The barrier height close to the critical flux decreases with the screening parameter as can be seen in Figure 3a increasing the escape probability near V_N^* where a local maximum $\beta = 12$ is reached. In the flux-tilted potential the particle is initially trapped in the well and the escape probability can be written as $P_e = 1 - \exp(-\Gamma_0 \Delta T)$ with $\Delta T = 10$ s, the time interval between points. To estimate the TAPJ probability, we consider the plasma frequency ω_p as the escape attempt frequency

$$\omega_p = \sqrt{\frac{2\pi I_c}{\Phi_0 C}} = \sqrt{\frac{\beta}{CL}} \tag{11}$$

which depends on the critical current and the junction capacitance. P_e is plotted in Figure 3b as a function of the flux difference $\Delta \Phi^* = \Phi_n - \Phi^*$ for $\beta = 4$ and 12. The junction capacitance $C \simeq 100$ fF was experimentally obtained in simultaneously patterned SN junctions from the hysteretic change of the critical current [11]. The expected potential of the system at V_N^* is plotted in Figure 3c for $\Phi_e = 0$, Φ_n^- and Φ^* with $P_e(\Phi^*) = 0.5$. The given phase-flux relation $\delta(\Phi)$ and the particle trajectories with and without TAPJ are plotted in Figure 3d. The differential resistance with a negative flux sweep polarity at V_N^* is plotted in Figure 3e. From the model, we estimated $\beta = 12$ and $\varphi_0 = -\pi$ considering the initial curvature and reminiscence of the resistance jumps. Although, the TAPJ estimation $\Delta \Phi^*$ reduces the high of the jumps, it does not explain why the system is not equally sensitive to TAPJ below V_N^{c1} as the potential is shifted by the extra phase, but $U_0(\Phi_n - \Phi^*)$ is φ_0 -invariant. The system is expected to be more sensitive to critical current fluctuations and environmental noise when the usual Josephson current is suppressed which could be also the origin of the decrease in sawtooth height around V_N^* . Further investigation with a more complex setup might shed some light on the phenomenon.



FIG. 4. φ_0 -evidence in quasi-1D HyQUID. (a) $\Delta V(V)$ using a flux-modulation readout. (b) Differential resistance $R_N(\Phi_e)$ of a flux-biased HyQUIDs for selected voltages. Non-hysteretic behavior and sawtooth profiles are consistent with a CPR dominated by the anomalous Josephson current $\varphi_0 = -\pi/2$ and negligible screening currents $\beta=1$. Curves are shifted for visualization.

IV. AJE IN QUASI-ONE-DIMENSIONAL HYQUIDS

Our wafer scale fabrication process gave us access to a considerable number of devices to validate the results presented in the main text with little variation in the critical voltage $V_N^{c1,c2}$. In this section we present results in flux-biased HyQUIDs with interferometer patterned by e-beam lithography. All the devices characterized with the flux-modulation readout depicted similarities to Figure 4a of the main text. $\Delta V(V_N)$ present two maxima with the same $V_N^{c1} = 6.5 \pm 0.5 E_{th}$ but larger V_N^{c2} $= 70\pm 2 E_{th}$. These results are understood by an interface transparency and diffusion coefficient similar to HyQUIDs with wider interferometers. The thermal nature of V_N^{c2} is confirmed in interferometers with $L_x = 1$ μ m junctions. $\Delta V(V_N)$ decay depends on the superconducting electrodes temperature $T_{sc}(V_N)$ which is lower in e-beam patterned samples due to the larger resistive thermal link. $\Delta V(V_N)$ and $R_N(\Phi)$ for selected voltages $V_N^{c1} < \mathcal{V} < V_N^{c2}$ are presented in Figure 4. The system is invariant with respect to the flux sweep polarity $R_N^-(\Phi) = R_N^+(\Phi) \ (\beta \sim 1)$ and the system is totally dominated by the anomalous Josephson current $\varphi_0 = -\pi/2$.

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